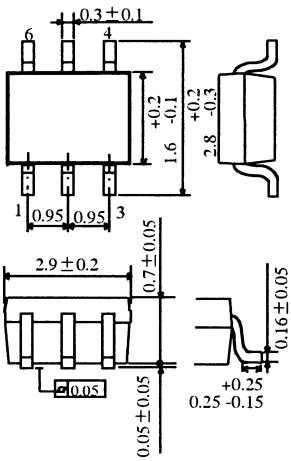
TOSHIBA Transistor Silicon PNP Epitaxial Type

TPC6603

Switching Applications
DC/DC Converter Applications
Strobe Flash Applications

- High DC current gain: h_{FE} = 200 to 500 (I_C = −0.5 A)
- Low collector-emitter saturation: $V_{CE\ (sat)}$ = −0.19 V (max)
- High-speed switching: t_f = 40 ns (typ.)

Unit: mm



1. Collector
2. Collector
3. Base
4. Emitter
5. Collector
6. Collector

JEDEC	—
JEITA	—
TOSHIBA	2-3T1A

Weight: 0.01 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	−30	V
Collector-emitter voltage		V_{CEO}	−20	V
Emitter-base voltage		V_{EBO}	−7	V
Collector current	DC	I_C	−3.0	A
	Pulse	I_{CP}	−5.0	
Base current		I_B	−0.3	mA
Collector power dissipation	DC	P_C (Note 1)	0.8	W
	t = 10 s		1.6	
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	−55 to 150	°C

Note 1: Mounted on an FR4 board (glass-epoxy; 1.6 mm thick; Cu area, 645 mm^2)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cutoff current		I_{CBO}	V_{CB} = −30 V, I_E = 0	—	—	−100	nA
Emitter cutoff current		I_{EBO}	V_{EB} = −7 V, I_C = 0	—	—	−100	nA
Collector-emitter breakdown voltage		$V_{(BR)\ CEO}$	I_C = −10 mA, I_B = 0	−20	—	—	V
DC current gain		h_{FE} (1)	V_{CE} = −2 V, I_C = −0.5 A	200	—	500	
		h_{FE} (2)	V_{CE} = −2 V, I_C = −1.6 A	100	—	—	
Collector-emitter saturation voltage		$V_{CE\ (sat)}$	I_C = −1.6 A, I_B = −53 mA	—	—	−0.19	V
Base-emitter saturation voltage		$V_{BE\ (sat)}$	I_C = −1.6 A, I_B = −53 mA	—	—	−1.10	V
Collector output capacitance		C_{ob}	V_{CB} = −10 V, I_E = 0, f = 1 MHz	—	28	—	pF
Switching time	Rise time	t_r	See Figure 1 circuit diagram $V_{CC} \simeq$ −12 V, R_L = 7.5 Ω $I_{B1} = -I_{B2}$ = −53.3 mA	—	70	—	ns
	Storage time	t_{stg}		—	150	—	
	Fall time	t_f		—	40	—	

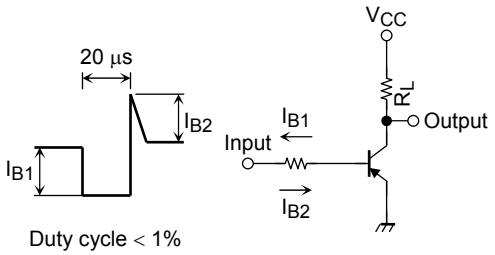
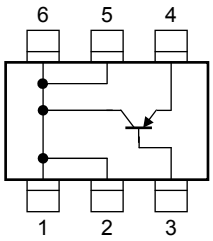
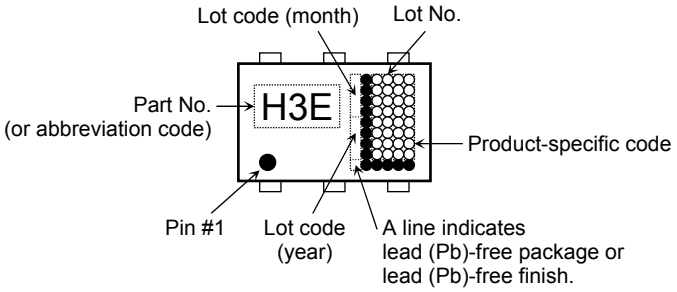


Figure 1. Switching Time Test Circuit

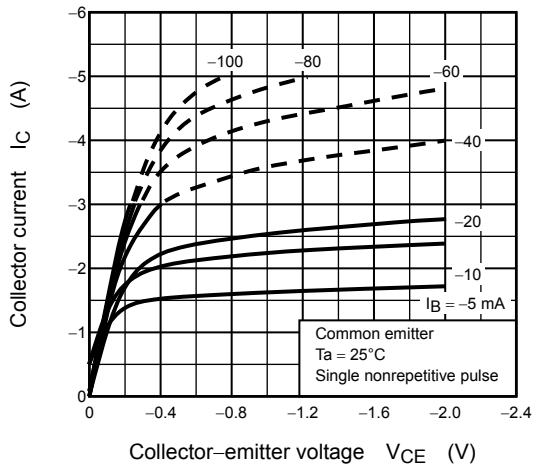
Circuit configuration (Top View)



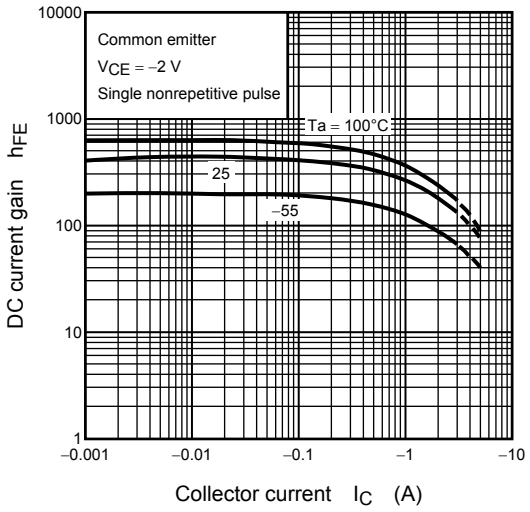
Marking



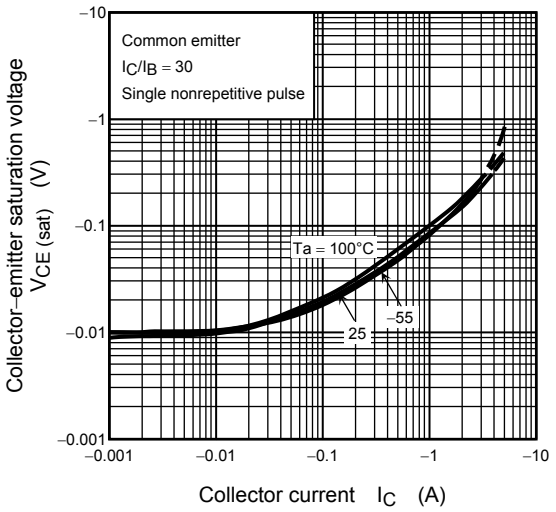
$I_C - V_{CE}$



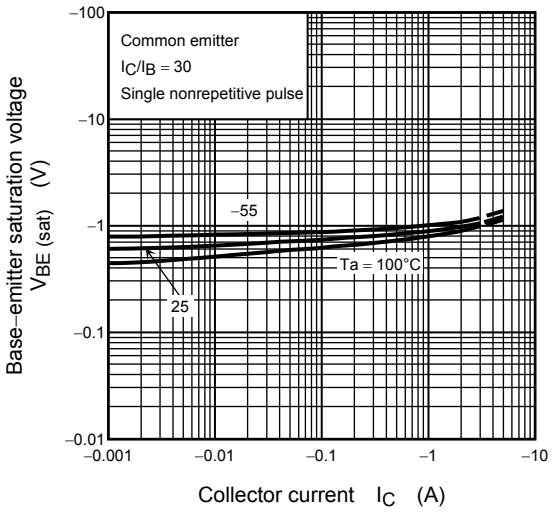
$h_{FE} - I_C$



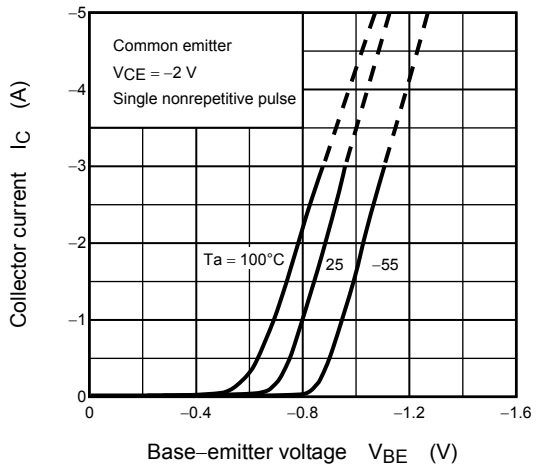
$V_{CE\ (sat)} - I_C$



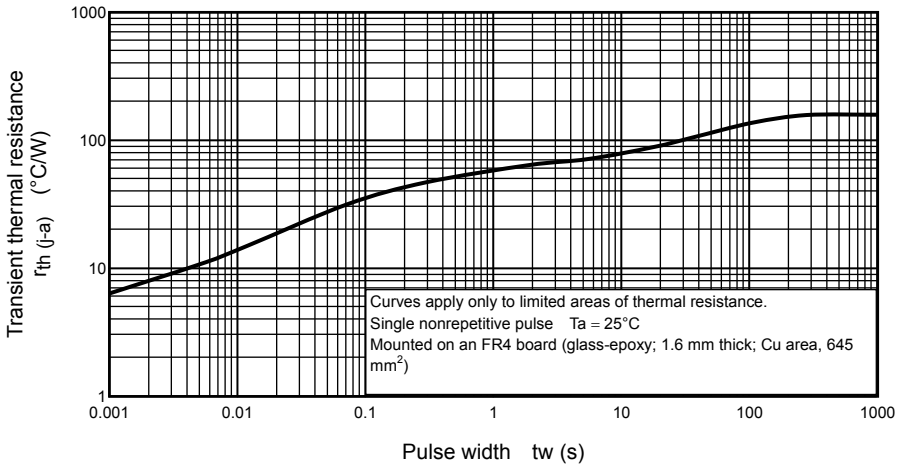
$V_{BE\ (sat)} - I_C$



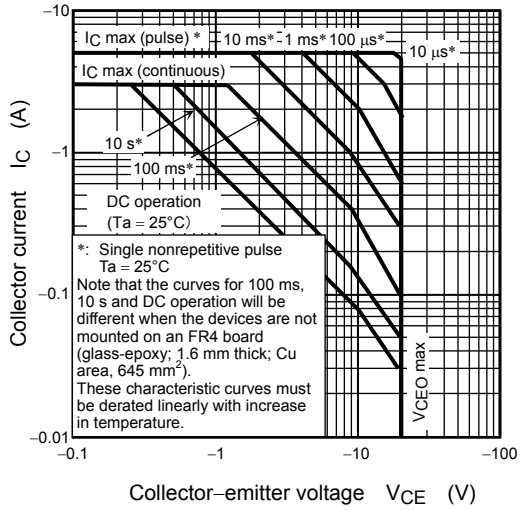
$I_C - V_{BE}$



$r_{th} - t_w$



Safe operating area



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